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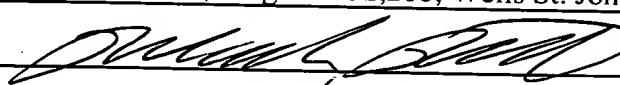
Application Number	09/943,190
Filing Date	August 29, 2001
First Named Inventor	Kristy A. Campbell
Group Art Unit	2818
Examiner Name	Unassigned

Attorney Docket Number MI22-1668

ENCLOSURES (check all that apply)

<input type="checkbox"/> Fee Transmittal Form <input type="checkbox"/> Fee Attached	<input type="checkbox"/> Assignment Papers (for an Application) <input type="checkbox"/> Drawing(s) <input type="checkbox"/> Licensing-related Papers <input type="checkbox"/> Petition Routing Slip (PTO/SB/69) and Accompanying Petition <input type="checkbox"/> Petition to Convert to a Provisional Application <input type="checkbox"/> Power of Attorney, Revocation Change of Correspondence Address <input type="checkbox"/> Terminal Disclaimer <input type="checkbox"/> Small Entity Statement <input type="checkbox"/> Request for Refund	<input type="checkbox"/> After Allowance Communication to Group <input type="checkbox"/> Appeal Communication to Board of Appeals and Interferences <input type="checkbox"/> Appeal Communication to Group (Appeal Notice, Brief, Reply Brief) <input type="checkbox"/> Proprietary Information <input type="checkbox"/> Status Letter <input checked="" type="checkbox"/> Additional Enclosure(s) (please identify below): <input type="checkbox"/> PTO return receipt postcard
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SIGNATURE OF APPLICANT, ATTORNEY, OR AGENT

Firm or Individual name	Mark S. Matkin; Reg. No. 32,268; Wells St. John P.S.
Signature	 8/20/02
Date	8/20/02

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UNITED STATES PATENT AND TRADEMARK OFFICE

EV07335147US

Patent Application Serial No. 09/943,190
Filing Date August 29, 2001
Inventorship Kristy A. Campbell et al.
Assignee Micron Technology, Inc.
Group Art Unit 2818
Examiner Unknown
Attorney's Docket No. MI22-1668
Title: Method of Forming Chalcogenide Comprising Devices, Method of
Forming a Programmable Memory Cell of Memory Circuitry, and a
Chalcogenide Comprising Device (as amended)

PRELIMINARY AMENDMENT SUBSEQUENT TO
AUGUST 29, 2001 FILING DATE

To: Assistant Commissioner for Patents
Attn: Art Unit 2818
Washington, D.C. 20231

From: Mark S. Matkin (Tel. 509-624-4276; Fax 509-838-3424)
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Subsequent to the filing of the above patent application on August 29, 2001, and prior to receipt of an Office Action on the merits, Applicant amends and remarks as follows:

AMENDMENTS

In the Title:

Please change the title to read as follows:

Method Of Forming Chalcogenide Comprising Devices,
Method Of Forming A Programmable Memory Cell Of
Memory Circuitry, And A Chalcogenide Comprising
Device